

Description

The 4N25, 4N26, 4N27, 4N28, 4N35, 4N36, 4N37, 4N38 series combine an AlGaAs infrared emitting diode as the emitter which is optically coupled to a silicon planar phototransistor detector in a plastic DIP6 package with different lead forming options.

Features

- High isolation 5000 VRMS
- DC input with transistor output
- Operating temperature range 55 °C to 110 °C
- RoHS & REACH Compliance
- MSL class 1
- UL-approved: UL1577, File No.E492440

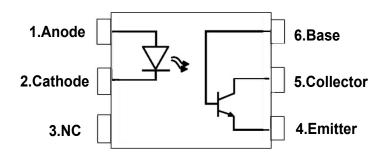
Truth Table (Positive Logic)

Input	Enable	Output		
Н	Н	L		
L	Н	Н		
Н	L	Н		
L	L	Н		
Н	NC	L		
L	NC	Н		

Applications

- Sequence controller
- Telephone/FAX
- System appliances, measuring instrument
- Programmable logic controller

Schematics





ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT	NOTE				
INPUT								
Forward Current	I _F	50	mA					
Peak Forward Current(t=10µs)	I _{FM}	1	Α	1				
Reverse Voltage	V _R	6						
Power Dissipation(TA=25°C)	P _D	70	mW					
OUT	OUTPUT							
Collector - Emitter Voltage	V _{CEO}	80	V					
Collector-Base Breakdown Voltage	V _{CBO}	80	V					
Emitter - Collector Voltage	V _{ECO}	7	V					
Emitter-Base Breakdown Voltage	V _{EBO}	7	V					
Collector Current	Ic	80	mA					
Power Dissipation(TA=25°C)	Pc	150	mW					
COMMON								
Total Power Dissipation	Ptot	200	mW					
Isolation Voltage	Viso	5000	Vrms	2				
Operating Temperature	Topr	-55~+110	°C					
Storage Temperature	Tstg	-55~+110	°C					
Soldering Temperature	Tsol	260	°C					

Note 1. AC For 1 Minute, R.H. = $40 \sim 60\%$

Note 2. For 10 seconds



ELECTRICAL OPTICAL CHARACTERISTICS at Ta=25°C

ELECTRICAL OF HOME CHARACTERIOTICS At 14 25 C							
PARAMETER	SYMBOL	MIN	TYP.	MAX	UNIT	TEST CONDITION	NOTE
INPUT							
Forward Voltage	V _F	-	1.24	1.4	V	IF=10mA	
Reverse Current	I _R	-	-	10	μA	VR=6V	
Input	Cin		30	20	рF	\/_0 f_4 . -	
Capacitance	CIII	-	30	30 -		V=0, f=1kHz	
			OUTP	JT			
Collector Dark	l		-	20	nA	VCE=10V, IF=0	
Current	I _{CEO}	-				VGE-10V, IF-0	
Collector-Emitter							
Breakdown	BV _{CEO}	80 -	-	-	- V	IC=1mA, IF=0	
Voltage							
Emitter-Collector							
Breakdown	BV _{ECO}	7	7 -	-	V	IE=1mA, IF=0	
Voltage							
Collector-Base	BV _{CBO}	80		-	V	IC= 0.1mA, IF=0	
Breakdown	D A CRO	00			V		
Emitter-Base	BV _{EBO}	7			V	IE= 0.1mA,IF=0	
Breakdown	D A FRO	'	_	_	V	IE- U. IIIIA, IP-U	



TRANSFER CHARACTERISTICS

TO WELL CHANGE THE							
Current		4N35, 4N36, 4N37	100	-	1		
Transfer	CTR	4N25,4N26, 4N38	20	-	ı	%	IF=10mA, VCE=10V
Ratio		4N27, 4N28	10	-	•		
		4N25,4N26,		-	0.5		IE-40: A \/OE-40\/
Collector-Emitt		4N27,4N28	-				IF=10mA, VCE=10V
er	V _{CE(sat)}	4N35,4N36,4N37	-	-	0.3	V	IF= 10mA, IC= 0.5mA
Saturation		4N38	-	-	1.0	V	IF= 20mA, IC= 4mA
Voltage		4N25,4N26,			٥.		IF- F0 A IO- 0 A
		4N27,4N28	-	- 0.5			IF= 50mA, IC= 2mA
Isolation	Rio		10^1	40444		Ω	\\ F00\\
Resistance			2	10^14	-		Vio=500Vdc.
Floating				0.2	1	ьг	\/-0 f-1\/\-7
Capacitance	C_IO		-	0.2	ı	pF	V=0, f=1MHz
Cut-off	fc		-	6	6 -	- kHz	VCE=5V, IC=2mA
Frequency							RL=100Ω,-3dB
Turn On Time		4N25,4N26,4N27,		0	15	-	IF= 10mA, VCC=
	t _{on}	4N28	-	3	15		10V, RL= 100Ω
		4N35,4N36,4N37,	-	10	12	-	Ic= 2mA, VCC= 10V,
		4N38					RL= 100Ω
Turn Off Time	t _{off}	4N25,4N26,4N27,	-	3	16	-	IF= 10mA, VCC=
		4N28					10V, RL= 100Ω
		4N35,4N36,4N37,	· -	9	12	-	Ic= 10mA, VCC= 10V,
		4N38					RL= 100Ω



CHARACTERISTIC CURVES

Fig.1 Forward Current vs. Ambient Temperature

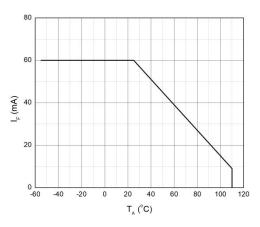


Fig.3 Forward Current vs. Forward Voltage

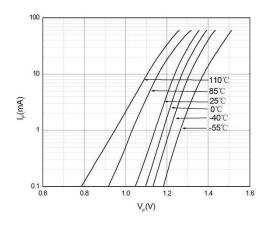


Fig.5 Collector Current vs. Collector-emitter Voltage

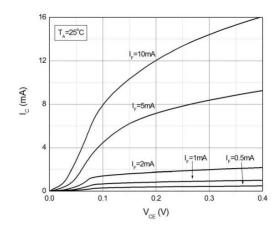


Fig.2 Collector Power Dissipation vs. Ambient Temperature

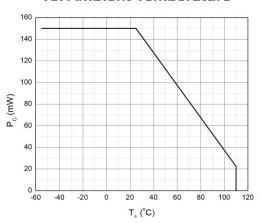


Fig.4 Collector Dark Current vs. Ambient Temperature

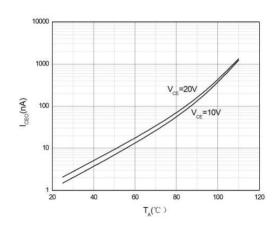
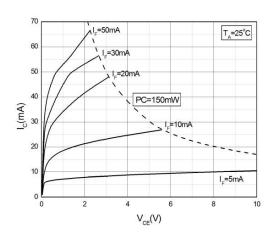


Fig.6 Collector Current vs. Collector-emitter Voltage





CHARACTERISTIC CURVES

Fig.7 Normalized Current Transfer Ratio vs. Forward Current

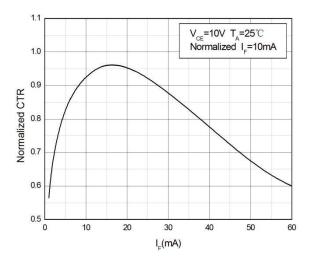


Fig.9 Current Transfer Ratlo(Unsaturated) vs
Base-Emitter Resistance

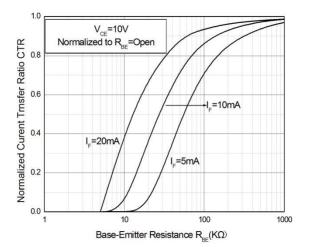


Fig.8 Normalized Current Transfer Ratio vs. Ambient Temperature

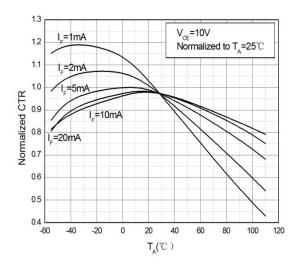
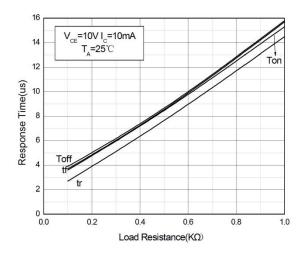
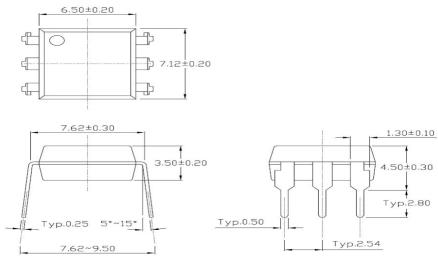


Fig.10 Switching Time vs. Load Resistance



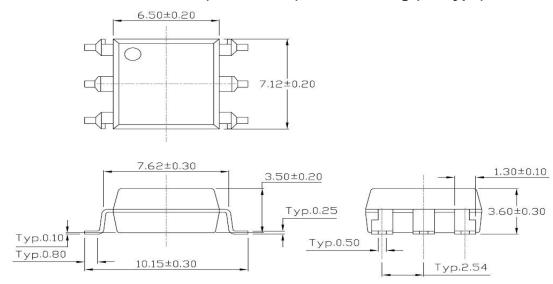


PACKAGE DIMENSIONS (Dimensions in mm unless otherwise stated) Standard DIP – Through Hole (DIP Type)

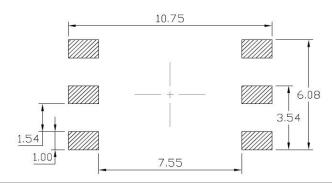


Gullwing (400mil) Lead Forming – Through Hole (M Type)

PACKAGE DIMENSIONS (Dimensions in mm unless otherwise stated) Surface Mount (Low Profile) Lead Forming (SL Type)

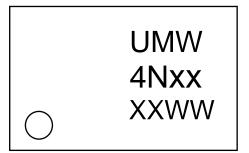


Recommended Solder Mask (Dimensions in mm unless otherwise stated) Surface Mount Lead Forming & Surface Mount (Low Profile) Lead Forming





Marking



- "XX" denotes YEAR;
- " WW" denotes WEEK

ORDERING INFORMATION

Order code	Package	Baseqty	Deliverymode
UMW 4N25SM	SOP-6	1000	Tape and reel
UMW 4N26SM	SOP-6	1000	Tape and reel
UMW 4N27SM	SOP-6	1000	Tape and reel
UMW 4N28SM	SOP-6	1000	Tape and reel
UMW 4N35SM	SOP-6	1000	Tape and reel
UMW 4N36SM	SOP-6	1000	Tape and reel
UMW 4N37SM	SOP-6	1000	Tape and reel
UMW 4N38SM	SOP-6	1000	Tape and reel
UMW 4N25	DIP-6	1600	Tube and box
UMW 4N26	DIP-6	1600	Tube and box
UMW 4N27	DIP-6	1600	Tube and box
UMW 4N28	DIP-6	1600	Tube and box
UMW 4N35	DIP-6	1600	Tube and box
UMW 4N36	DIP-6	1600	Tube and box
UMW 4N37	DIP-6	1600	Tube and box
UMW 4N38	DIP-6	1600	Tube and box